1 : Gate 2 : Drain 3 : Sourse

SANYO: TO-220ML





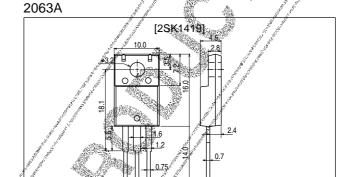
Ultrahigh-Speed Switching Applications

Features

- · Low ON resistance.
- · Ultrahigh-speed switching.
- · Converters.
- · Micaless package facilitating mounting.

Package Dimensions

unit:mm



Specifications

Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Ratings	Unit
Drain-to-Source Voltage	V _{D\$\$}	60	V
Gate-to-Source Voltage	Véss //	±20	V
Drain Current (DC)	/ Jb	15	Α
Drain Current (Pulse)	/ I _{DP} PW≤10 is duty cycle≤1%	60	Α
Allowable Power Dissipation	Tc≅25°C	25	W
		2.0	W
Channel Temperature	// Tche	150	°C
Storage Temperature	// Estg	-55 to +150	°C

Electrical Characteristics at Ta = 25°C

	7.55	- Carlotte State				
Parameter	Symbol Conditions -	Ratings			Unit	
Tarameter		2 /	min	typ	max	Offic
Drain-to-Source Breakdown Voltage	V(BR)DSS	ID=1mA, V _{GS} =0	60			V
Zero-Gate Voltage Drain/Current	IDSS	V _{DS} =60V, V _{GS} =0			100	μΑ
Gate-to-Source Leakage Current	IG\$S.	$V_{GS}=\pm20V$, $V_{DS}=0$			±100	nA
Cutoff Voltage	VGS(off)	$V_{DS}=10V$, $I_{D}=1mA$	1.5		2.5	V
Forward Transfer Admittance	yfs	$V_{DS}=10V$, $I_{D}=10A$	6.0	10		S
Static Drain-to-Source ON-State Resistance	RDS(on)	I _D =10A, V _{GS} =10V		60	80	mΩ

(Note) Be careful in handling the 25K1419 because it has no protection diode between gate and source.

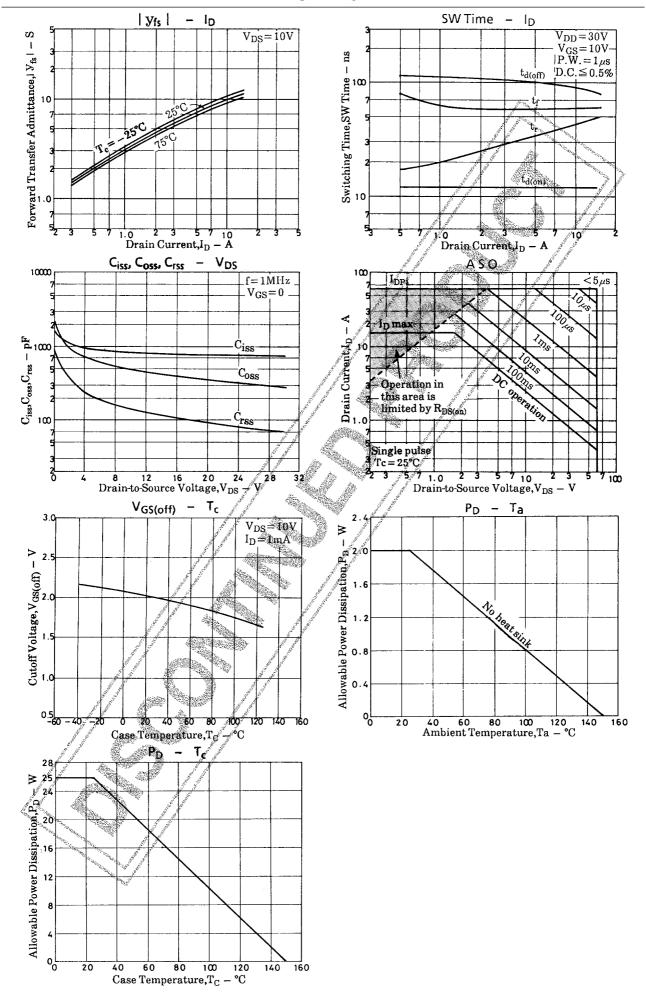
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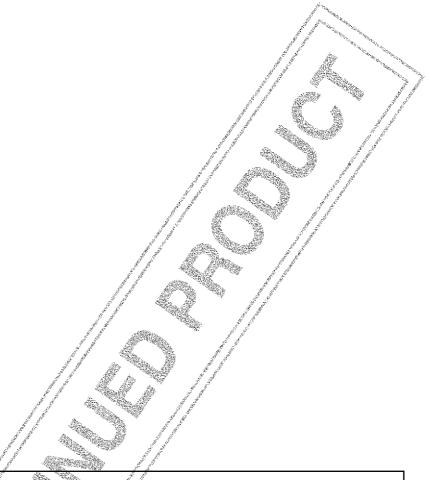
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Continued from preceding page.

Parameter	Symbol	Conditions	Ratings			Unit
Falametel			min	typ	max	01111
Input Capacitance	Ciss	V _{DS} =20V, f=1MHz		750		pF
Output Capacitance	Coss	V _{DS} =20V, f=1MHz		350		pF
Reverse Transfer Capacitance	Crss	V _{DS} =20V, f=1MHz	1	90		pF
Turn-ON Delay Time	t _d (on)	I_D =10A, V_{GS} =10V, V_{DD} =30V, R_{GS} =50 Ω	and the second	12		ns
Rise Time	t _r	I_D =10A, V_{GS} =10V, V_{DD} =30V, R_{GS} =50 Ω	N. F	.43	CENTRAL SEC.	ns
Turn-OFF Delay Time	td(off)	I _D =10A, V _{GS} =10V, V _{DD} =30V, R _{GS} =50Ω		90	AND THE PROPERTY OF	ns
Fall Time	t _f	I _D =10A, V _{GS} =10V, V _{DD} =30V, R _{GS} =50Ω		60	ON PROPERTY.	ns
Diode Forward Voltage	V _{SD}	I _S =15A, V _{GS} =0	4 7000		1.8	V
		A A	- 10 STATE	29,20	39	8

Switching Time Test Circuit VDD=30V Vin 10V JL I D = 10 A R_L=3Ω - ∨auт D.C. ≦0.5% P.G 2SK1419 50₽ I_D - V_{DS} - V_{GS} ID 20 $V_{DS} = 10V$ Drain Current, $I_D - A$ Drain Current, ID 3.5V o_r Drain-to-Source Voltage, V_{DS} Gate-to-Source Voltage, $V_{GS} - V$ R_{DS(on)} VGs $R_{DS(on)} - T_c$ 280 140 $T_c = 25^{\circ}C$ $I_D = 10A$ $I_{D} = 10A$ $V_{GS} = 10V$ Static Drain-to-Source ON-State Resistance, $R_{DS}(on) - m\Omega$ δ δ δ δ δ δ δ ٥٢ 060 -40 -20 0 20 40 60 80 100 120 140 160 Case Temperature, T_C - °C Gate-to-Source Voltage, V_{GS} - V 14





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